RingRAM: A Unified Hardware Security Primitive for IoT Devices that Gets Better with Age

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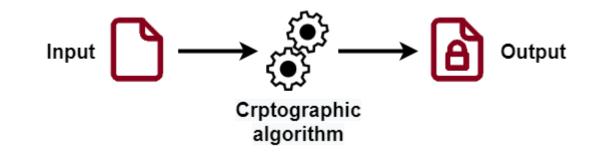
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Security depends on non-determinism

- Cryptographic algorithms
 - Deterministic by design
 - Same inputs = same output

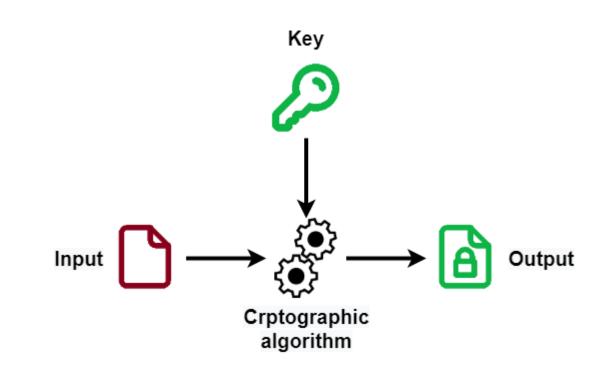




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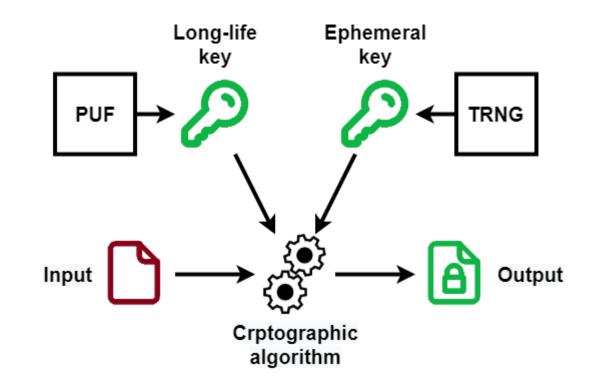
- Key
 - Non-deterministic
 - Adds security





There are two types of keys

- Long-life keys
 - Pre-shared keys
 - Device fingerprint
 - Private key
- Ephemeral keys
 - Generated continuously
 - Key agreement protocol



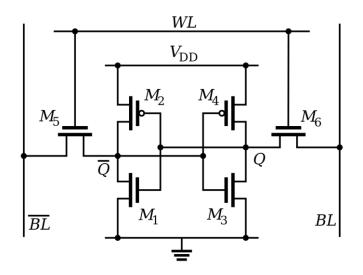


PUFs provide long-life keys

• Fingerprints

- Device-specific identifier
- Harnesses manufacturing-time chaos
- Depends on within-chip variation
- SRAM
 - Leverages power-on state

6T SRAM cell



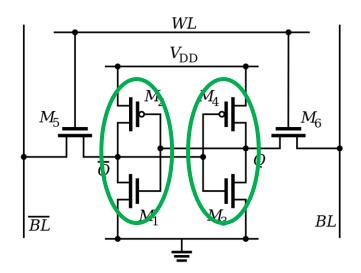


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TRNGs provide ephemeral keys

• Entropy

- Accumulated operational chaos
- Ideally high-rate and unbounded

- Ring Oscillators (RO)
 - Frequency variation

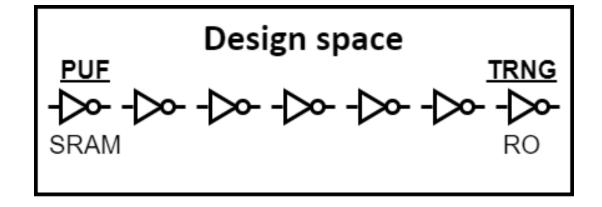


IoT demands a unified hardware security primitive

- Advantage
 - Reduced overhead (power, area, cost)
 - Cross integrity validation



- Trade Space: SRAM vs RO
 - Different forms of chaos
 - Captured using inverters



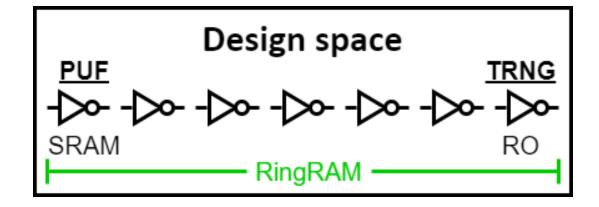


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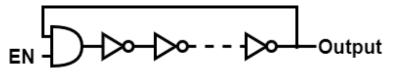


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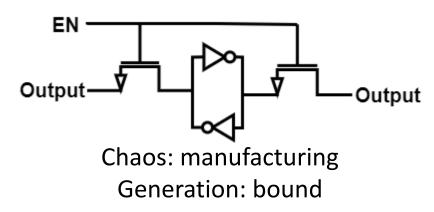


RingRAM is a best-of-breed combination of RO and SRAM



RO

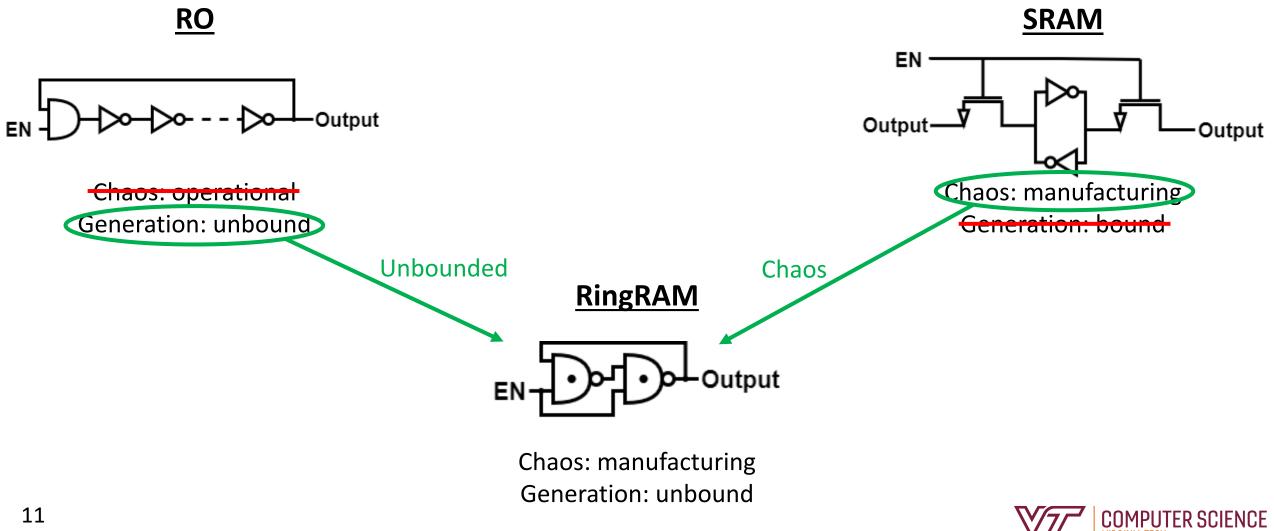
Chaos: operational Generation: unbound



SRAM

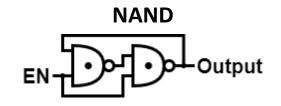


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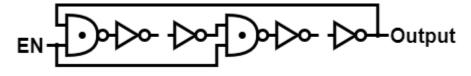


Exposing the PUF/TRNG design space

- Observation: increasing inverters per chain normalizes propagation delay
- Result: longer chains increase proportion of TRNG cells



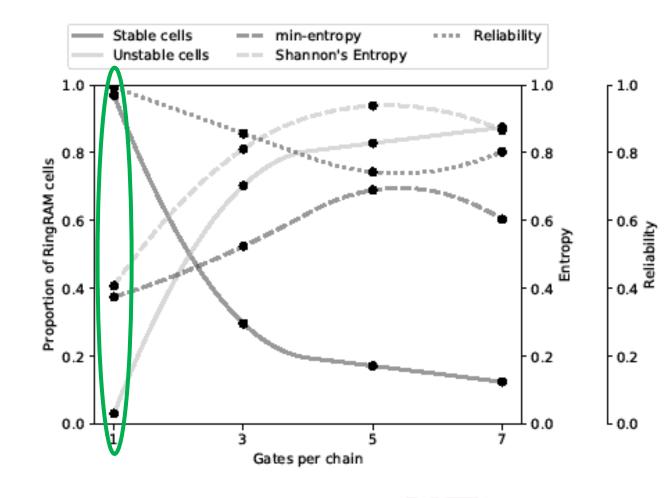
NAND + even number of inverters





Exposing the PUF/TRNG design space

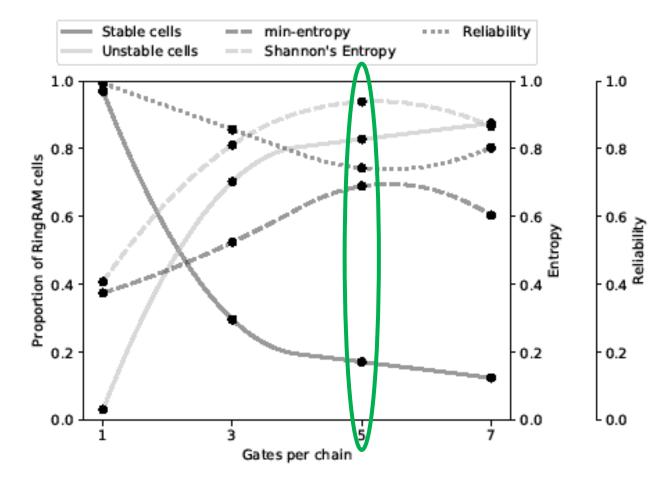
- Controlling composition
 - Number of gates per chain
 - Explore trade-space
- Single NAND gate
 - Highly stable cells
 - Great for PUFs
 - Not great for TRNGs





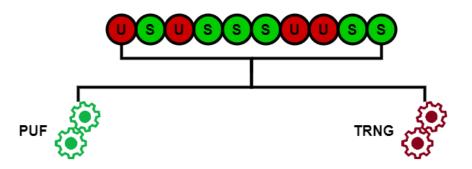
Exposing the PUF/TRNG design space

- Controlling composition
 - Number of gates per chain
 - Explore trade-space
- NAND gate + 4 inverters
 - High TRNG entropy
 - Good PUF reliability



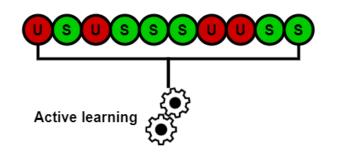


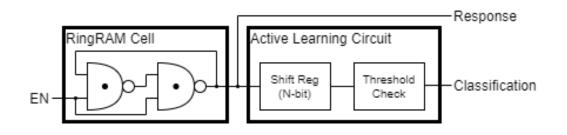
- PUFs want less noise
- TRNGs want more noise





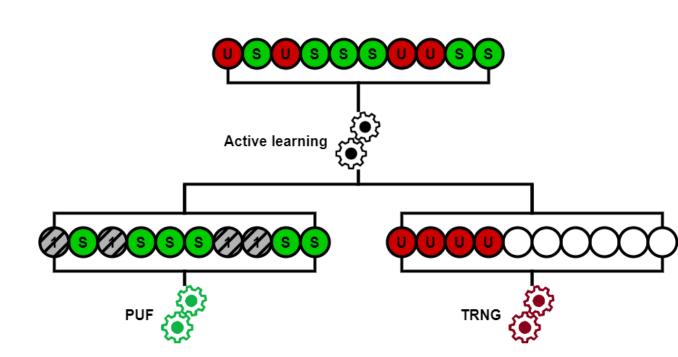
- PUFs want less noise
- TRNGs want more noise
- Active learning:
 - Classifies cells dynamically
 - Shift reg: stores response
 - Threshold check: shift reg bias





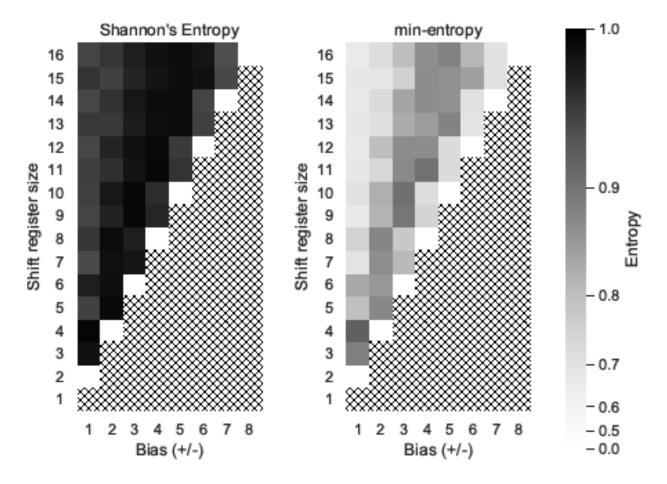


- PUFs want less noise
- TRNGs want more noise
- Active learning:
 - Classifies cells
 - PUFs only output stable
 - TRNGs only output unstable





- PUFs want less noise
- TRNGs want more noise
- Active learning design space exploration
 - Examine entropy
 - Vary bias and shift reg

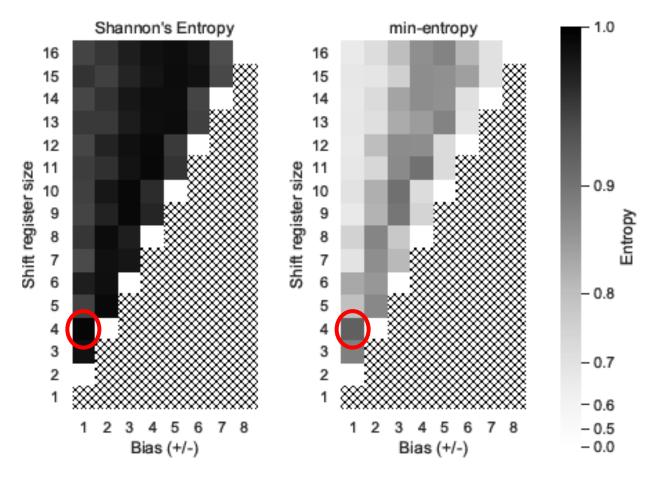




• Issue:

- PUFs want less noise
- TRNGs want more noise
- Active learning design space exploration
 - Examine entropy
 - Vary bias and shift reg

Optimal design: 4 shift reg ±1 bias

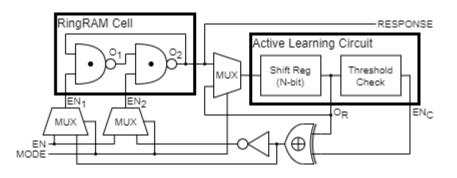




Making age a strength

• Aging:

- All electronic devices age
- Use dependent
- Active aging:
 - Stable cells increase bias for PUFs
 - Unstable cells decrease bias for TRNGs





RingRAM is an effective PUF

• Reliability: produce the same responses

$$100\% - \frac{1}{m} \sum_{i=1}^{m} \frac{HD(R_0, R_i)}{n} \times 100\%$$

• Uniformity: produce balanced responses

$$\frac{1}{m} \sum_{i=1}^{m} \frac{HW(R_i)}{n} \times 100\%$$

| Metric | RO | SRAM | RingRAM |
|-------------------------|--------|--------|---------|
| Reliability | 99.10% | 92.20% | 98.40% |
| Uniformity | 49.40% | 48.70% | 48.20% |
| Uniqueness | 47.20% | 48.70% | 48.40% |
| Transistors/unified bit | 1641.1 | 99.75 | 88.5 |

• Uniqueness: dependency on placement

$$\frac{2}{c(c-1)} \sum_{i=1}^{c-1} \sum_{j=i+1}^{c} \frac{HD(R_i, R_j)}{n} \times 100\%$$



RingRAM is an effective TRNG

• Min-entropy: worst-case

 $log_2 \frac{1}{P_{MAX}(x)}$

• Shannon's Entropy: average case

$$-\sum_{i=0}^{n} P(x_i) \log_2 P(x_i)$$

| Metric | RO | SRAM | RingRAM |
|-------------------------|--------------|-------|--------------|
| Unbounded | \checkmark | × | \checkmark |
| Throughput | 38M | N/A | 228M |
| min-entropy | 0.97 | 0.031 | 0.981 |
| Shannon's Entropy | 0.99 | 0.058 | 0.999 |
| Transistors/unified bit | 1641.1 | 99.75 | 88.5 |

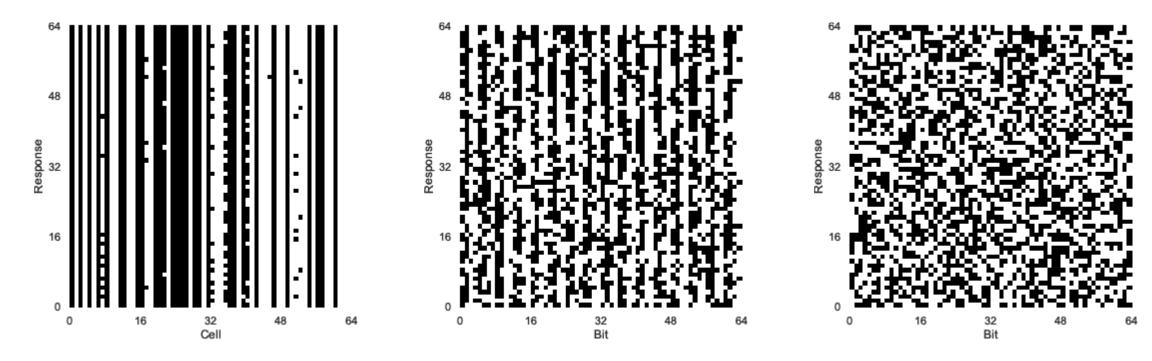


RingRAM is an effective TRNG

RingRAM

RingRAM + CC

RingRAM + CC + AL





RingRAM is resilient to thermal attacks

- Temperature:
 - Significant source of systematic run-time variation
- RingRAM's cross-coupled design:
 - Sensitive to manufacturing-time chaos
 - Naturally filters out systematic run-time variation
- Controlled thermal operation:
 - Ambient temperature: 0°C, 10°C, 20°C, 30°C, 40°C
 - PUF reliability: ±1.27%
 - TRNG entropy: ± 0.22%





RingRAM is secure

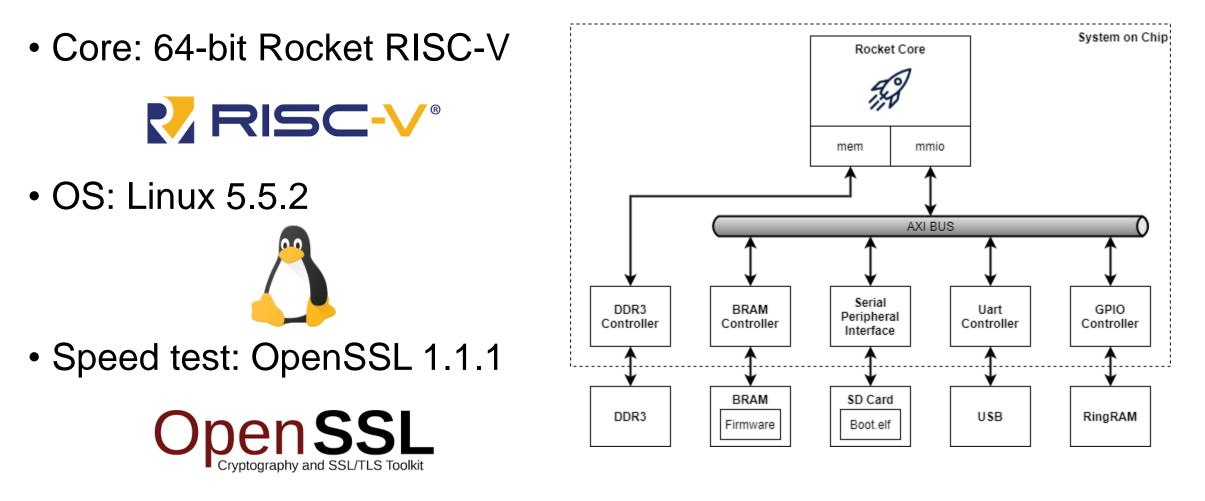
- Single-use
 - Read only to attacker
- Aging resilience

| Metric | RO | SRAM | RingRAM |
|--------------------------|--------------|--------------|--------------|
| Single-use | \checkmark | X | \checkmark |
| Aging Resilient | \checkmark | X | \checkmark |
| Thermal Resilient | X | \checkmark | \checkmark |
| Voltage Resilient | X | \checkmark | \checkmark |

- Active aging increases performance over time
- Thermal & voltage resilience
 - Tightly packed layout treats these as common-mode noise



RingRAM improves system security



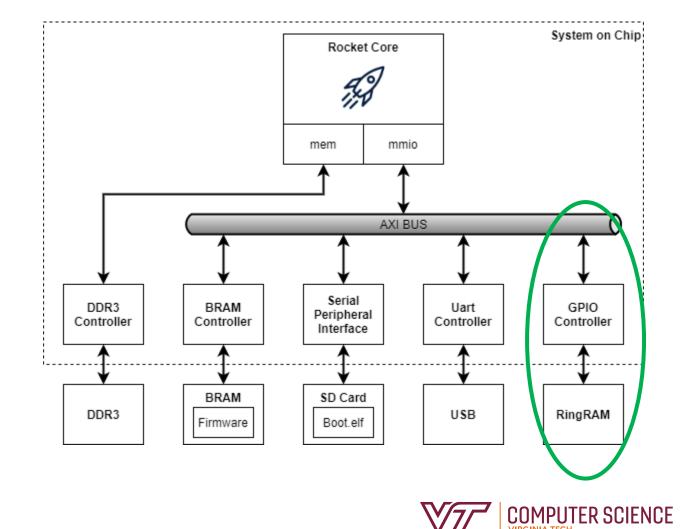


RingRAM improves system security

- Device drivers
 - /dev/random
 - /dev/urandom

OpenSSL speed test

| Test | RingRAM | Linux |
|----------|---------|-------|
| sha-512 | 0.00% | 0.13% |
| aes-192 | -0.05% | 0.03% |
| rsa-2048 | 0.00% | 0.00% |





Find RingRAM source code and FPGA prototypes at:

https://github.com/FoRTE-Research/RingRAM

